



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

Bl/cos Bost J						
BV _{DSS}	R _{DS(on) max}	T _C = +25°C				
700V	$1.3\Omega @ V_{GS} = 10V$	4.6A				

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

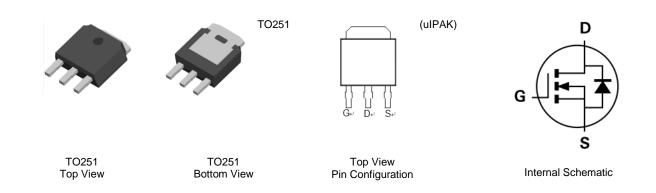
- Motor Control
- Backlighting
- AC-DC Converters

Features and Benefits

- Low On-Resistance
- High BVDss rating for power application
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO251
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMJ70H1D3SH3	TO251	75pieces / tube

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

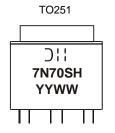
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information

Notes:



D! Hanufacturer's Marking 7N70SH = Product Type Marking Code YYWW = Date Code Marking YY or \underline{YY} = Last Digit of Year (ex: 15 = 2015) WW or WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	700	V	
Gate-Source Voltage		V _{GSS}	±30	V
Continuous Drain Current (Note 5) $V_{GS} = 10V$	T _C = +25°C T _C = +100°C	ID	4.6 2.9	А
Maximum Body Diode Forward Current (Note 6)		Is	3.0	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I _{DM}	5.4	A
Avalanche Current (Note 7)	L = 60mH	I _{AS}	1.1	A
Avalanche Energy (Note 7)	L = 60mH	E _{AS}	40	mJ
Peak Diode Recovery dv/dt (Note 7)	•	dv/dt	5	V/ns

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Total Power Dissipation (Note 5)	$T_{\rm C} = +25^{\circ}{\rm C}$	D	41	W	
Total Power Dissipation (Note 5)	$T_{\rm C} = +100^{\circ}{\rm C}$	PD	16	vv	
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	79	°C/W		
Thermal Resistance, Junction to Case (Note 5)	R _{θJC}	3.0	C/W		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

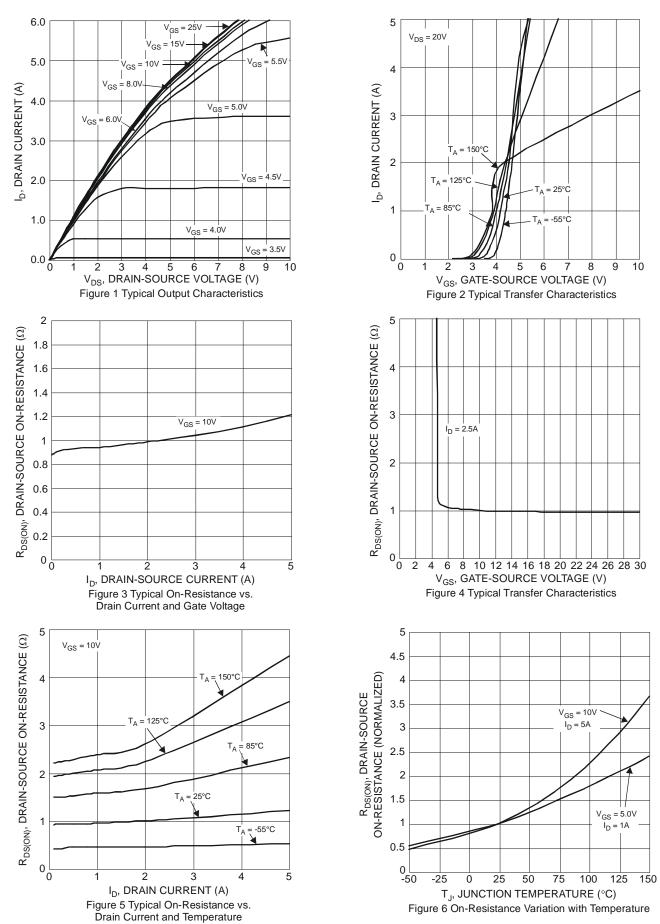
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	• • • • • •		- 76		•		
Drain-Source Breakdown Voltage	BV _{DSS}	700			V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_		1	μA	V _{DS} = 700V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_		100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	2	2.9	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.0	1.3	Ω	$V_{GS} = 10V, I_D = 2.5A$	
Diode Forward Voltage	V _{SD}	_	0.9	1.3	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	351	_		V _{DS} = 50V, f = 1MHz, V _{GS} = 0V	
Output Capacitance	Coss		66	_	pF		
Reverse Transfer Capacitance	Crss	_	1.1	_			
Gate Resistance	R _G	_	3.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	13.9	_		$V_{DD} = 560V, I_{D} = 5A,$	
Gate-Source Charge	Qgs	_	1.9	_	nC	$v_{DD} = 560v, i_D = 5A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}	_	8.5	_		VGS = 10V	
Turn-On Delay Time	t _{D(on)}	_	8.5	_			
Turn-On Rise Time	tr	_	11.6	_	-	$V_{DD} = 350V, V_{GS} = 10V,$ $R_G = 4.7\Omega, I_D = 2.5A$	
Turn-Off Delay Time	t _{D(off)}	_	24.5	_	ns		
Turn-Off Fall Time	t _f	_	10	_			
Body Diode Reverse Recovery Time	t _{rr}		212		ns		
Body Diode Reverse Recovery Time (T _J = +150°C)	t _{rr}		251	_	ns		
Body Diode Reverse Recovery Charge	Q _{rr}		1.8	_	μC	$I_{\rm S} = 5A, dI/dt = 100A/\mu s$	
Body Diode Reverse Recovery Charge $(T_J = +150^{\circ}C)$	Q _{rr}	_	2.3		μC	\neg	

Notes:

Device mounted on infinite heatsink.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Guaranteed by design. Not subject to production testing.
 Short duration pulse test used to minimize self-heating effect.

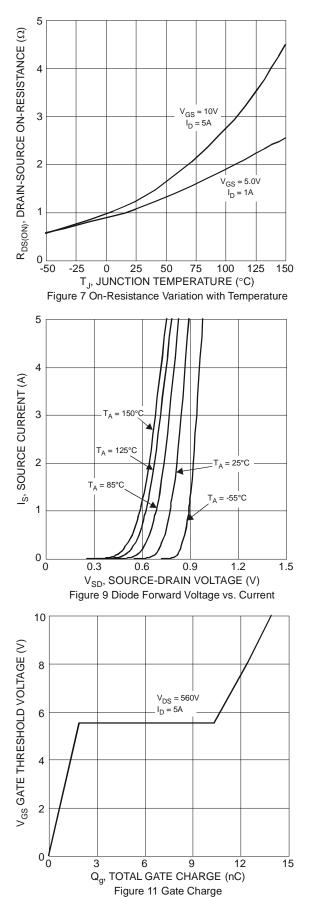


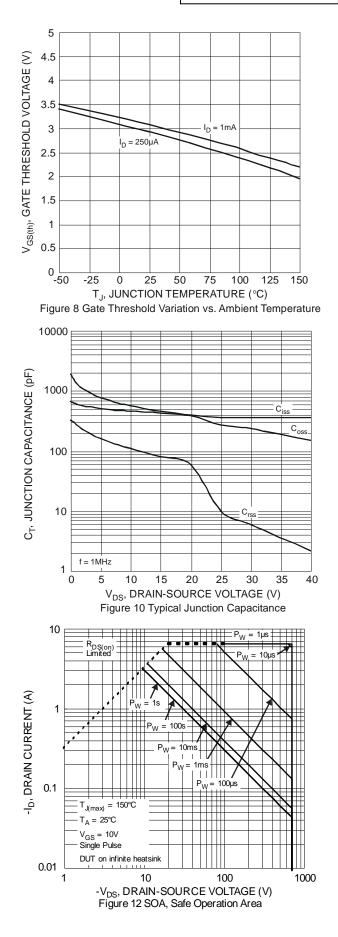
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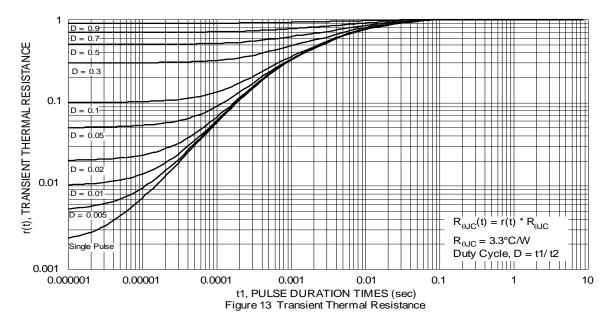
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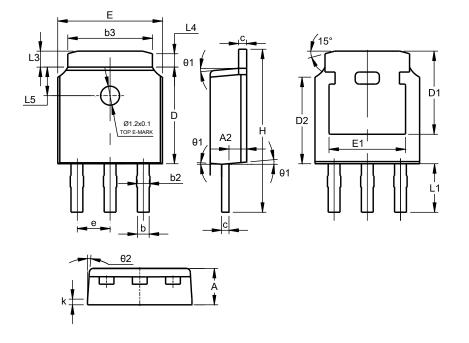






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	TO251 (Type TH3)					
Dim	Min	Max	Тур			
Α	2.20	2.40	2.30			
A2	0.97	1.17	1.07			
b	0.68	0.90	0.78			
b2	0.76	0.95	0.84			
b3	5.20	5.50	5.33			
С	0.43	0.63	0.53			
D	5.98	6.22	6.10			
D1	5	5.30 REF				
D2	5.26	5.66	5.46			
е	2.	286 BS	C			
ш	6.40	6.80	6.60			
E1	4.63	5.03	4.83			
Н	9.40	9.85	9.62			
k	0	0.40REF				
L1	2.30	2.70	2.50			
L3	0.88	1.28	1.02			
L4	0.75 REF					
L5	1.65	1.95	1.80			
θ1	5°	9°	7°			
θ2	5°	9°	7°			
All D	All Dimensions in mm					



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